SN54ALVTH162244, SN74ALVTH162244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCES074E - JUNE 1996 - REVISED JANUARY 1999

- State-of-the-Art Advanced BiCMOS Technology (ABT) Widebus™ Design for 2.5-V and 3.3-V Operation and Low Static **Power Dissipation**
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- **Power Off Disables Outputs, Permitting Live Insertion**
- **High-Impedance State During Power Up** and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to **Prevent the Bus From Floating**
- Output Ports Have Equivalent 30- Ω Series Resistors, So No External Resistors Are Required
- **Auto3-State Eliminates Bus Current** Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates **Printed Circuit Board Layout**
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- **Package Options Include Plastic Shrink** Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

NOTE: For order entry:

The DGG package is abbreviated to G, and the DGV package is abbreviated to V.

description

The 'ALVTH162244 devices are 16-bit buffers/line drivers designed for low-voltage 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

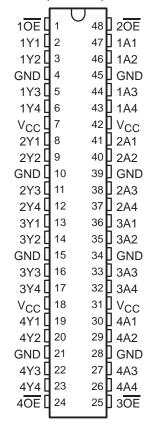


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SN54ALVTH162244 . . . WD PACKAGE SN74ALVTH162244 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



description (continued)

These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. These devices provide true outputs and symmetrical active-low output-enable (OE) inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

All outputs are designed to sink up to 12 mA and include equivalent 30-Ω resistors to reduce overshoot and undershoot.

The SN54ALVTH162244 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALVTH162244 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)

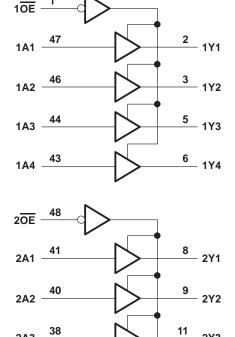
INP	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
Н	Χ	Z

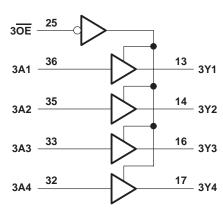
logic diagram (positive logic)

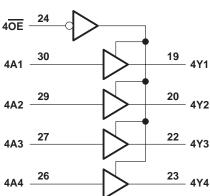
2A3

2A4 -

37









2Y3

- 2Y4

12

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	0.5 V to 7 V
Output current in the low state, I _O	30 mA
Output current in the high state, I _O	
Input clamp current, I_{IK} ($V_I < 0$)	
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
DL package	94°C/W
Storage temperature range, T _{stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54A	LVTH16	62244	SN74A	LVTH16	2244	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		2.3		2.7	2.3		2.7	V
VIH	High-level input voltage		1.7		1/2	1.7			V
V _{IL}	Low-level input voltage			Z.	0.7			0.7	V
VI	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
loн	High-level output current			1	-6			-8	mA
loL	Low-level output current			2	8			12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	0/0/	7	10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate	·	200			200		·	μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions, V_{CC} = 3.3 V \pm 0.3 V (see Note 3)

			SN54ALVTH16		SN54ALVTH162244		SN74ALVTH162244		
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		3		3.6	3		3.6	V
VIH	High-level input voltage		2		7	2			V
V _{IL}	Low-level input voltage			Š	0.8			0.8	V
VI	Input voltage		0	Vcc.	5.5	0	VCC	5.5	V
loн	High-level output current			7	-8			-12	mA
l _{OL}	Low-level output current			25	8			12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		5	10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54/	ALVTH1	62244	SN74ALVTH162244		UNIT		
		TEST COND	ITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT	
VIK		$V_{CC} = 2.3 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0.	.2		V _{CC} -0	.2			
Vон		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.7						V	
		VCC = 2.5 V	$I_{OH} = -8 \text{ mA}$				1.7				
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OL} = 100 \mu A$			0.2			0.2		
VOL		V _{CC} = 2.3 V	I _{OL} = 8 mA			0.7				V	
		VCC = 2.3 V	I _{OL} = 12 mA						0.7		
	Control	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1		
	inputs	V _{CC} = 0 or 2.7 V,	V _I = 5.5 V			10			10		
lį			V _I = 5.5 V			10			10	μΑ	
	Data inputs	Data inputs V _{CC} = 2.7 V	VI = VCC			\$ 1			1		
			V _I = 0		1	- 5			- 5		
l _{off}		$V_{CC} = 0$,	V_{I} or $V_{O} = 0$ to 4.5 V		77.6				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	V _I = 0.7 V		115			115		μΑ	
I _{BHH} §		$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V		S –10			-10		μΑ	
IBHLO	T	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300	Ò,		300			μΑ	
Івнно		$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ	
IEX		V _{CC} = 2.3 V,	V _O = 5.5 V			125			125	μΑ	
I _{OZ(PU}	l/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V to V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = \text{don'} i$	CC, t care			±100			±100	μА	
lozh		V _{CC} = 2.7 V	V _O = 2.3 V, V _I = 0.7 V or 1.7 V			5			5	μА	
lozL		V _{CC} = 2.7 V	V _O = 0.5 V, V _I = 0.7 V or 1.7 V			- 5			-5	μΑ	
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1		
ICC		$I_{O} = 0$	Outputs low		2.3	4.5		2.3	4.5	mA	
		$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3			3		pF	
Co		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		6			6		pF	

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#] An external driver must sink at least IBHHO to switch this node from high to low.

 $[\]parallel$ Current into an output in the high state when $\vee_{O} > \vee_{CC}$

^{*}High-impedance state during power up or power down

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

DA	DAMETED	TEST OF	TEST CONDITIONS		62244	SN74	ALVTH16	62244	UNIT	
PA	RAMETER	TEST CC	CNDITIONS	MIN TYPT	MAX	MIN	TYP [†]	MAX	UNII	
٧ıK		V _{CC} = 3 V,	I _I = -18 mA		-1.2			-1.2	V	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.2		V _{CC} -0	.2			
VOH		VCC = 3 V	$I_{OH} = -8 \text{ mA}$	2					V	
		ACC = 2 A	$I_{OH} = -12 \text{ mA}$			2				
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA		0.2			0.2		
VOL		VCC = 3 V	$I_{OL} = 8 \text{ mA}$		0.8				V	
		VCC = 3 V	$I_{OL} = 12 \text{ mA}$					0.8		
	Control	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		±1			±1		
	inputs	V _{CC} = 0 or 3.6 V	V _I = 5.5 V		10			10		
lį			V _I = 5.5 V		10			10	μΑ	
	Data inputs	V _{CC} = 3.6 V	$\Lambda^{I} = \Lambda^{CC}$		\$ 1			1		
			V _I = 0	,	- 5			– 5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	Q.				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 3 V$	V _I = 0.8 V	75		75			μΑ	
I _{BHH} §		$V_{CC} = 3 V$,	V _I = 2 V	-75		-75			μΑ	
IBHLO	,¶	V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	500		500			μΑ	
Івннс) [#]	V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	-500		-500			μΑ	
ΙΕΧ		V _{CC} = 3 V,	V _O = 5.5 V		125			125	μΑ	
IOZ(Pl	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{OE} = 0.5 \text{ V}$	to V _{CC} , don't care		±100			±100	μΑ	
lozh		V _{CC} = 3.6 V	V _O = 3 V, V _I = 0.8 V or 2 V		5			5	μΑ	
lozL		V _{CC} = 3.6 V	V _O = 0.5 V, V _I = 0.8 V or 2 V		-5			- 5	μΑ	
		V _{CC} = 3.6 V,	Outputs high	0.07	0.1		0.07	0.1	mA	
ICC		$I_{O} = 0$,	Outputs low	3.2	5		3.2	5		
		$V_I = V_{CC}$ or GND	Outputs disabled	0.07	0.1		0.07	0.1		
∆lcc□	ı	V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or G			0.4			0.4	mA	
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0	3			3		pF	
Co		V _{CC} = 3.3 V,	V _O = 3.3 V or 0	6			6		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to VCC and then lowering it to VIH min.

[¶] An external driver must source at least IBHLO to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

[□]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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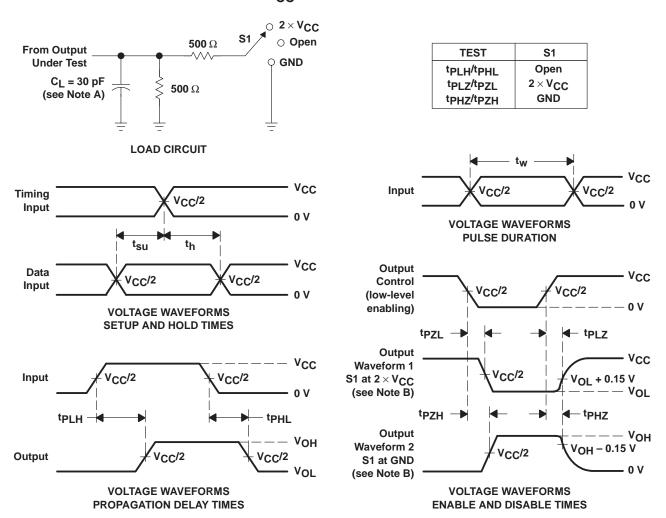
switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO		H162244	SN74ALVTH	1162244	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	۸		1	4.3	1	4.2	ns
^t PHL	А	1	1.4	3.8	1.5	3.7	115
^t PZH	ŌĒ		1.3	6.9	1.4	6.8	nc
t _{PZL}) OE	T I	1.3	5.2	1.4	5.1	ns
^t PHZ	ŌĒ	V	6	4.7	1	4.6	ns
^t PLZ	OE .	T	2 1	3.6	1	3.5	115

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVTH	162244	SN74ALVTI	1162244	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	۸	V	1	//3.4	1	3.3	ns
^t PHL	А	ı	1	3.4	1	3.3	115
^t PZH	ŌĒ	V	1.4	5	1.5	4.9	ns
^t PZL	OE .	Ť	1.3	3.4	1.4	3.3	115
^t PHZ	ŌĒ	V	1,4	5	1.5	4.9	ns
t _{PLZ}	OE .	ī	1.4	4.4	1.5	4.3	113

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

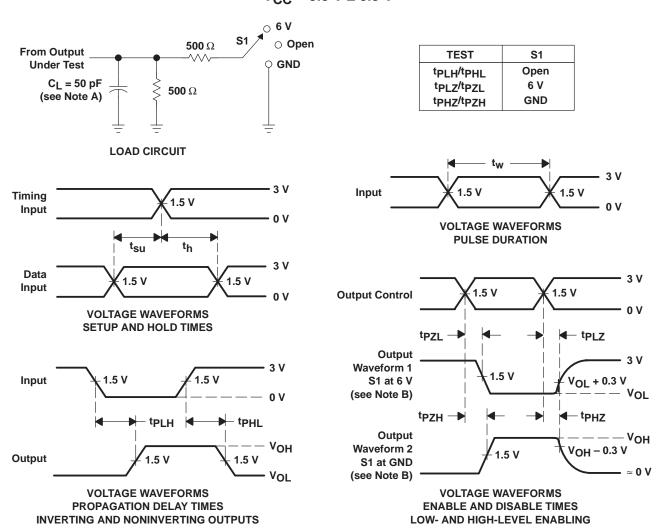


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION V_{CC} = 3.3 V \pm 0.3 V



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_f \leq 2.5 \,\text{ns}$, $t_f \leq 2.5 \,\text{ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms



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RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video and Imaging	www.ti.com/video
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